

50V NPN SILICON LOW SATURATION TRANSISTOR IN SOT23

Features and Benefits

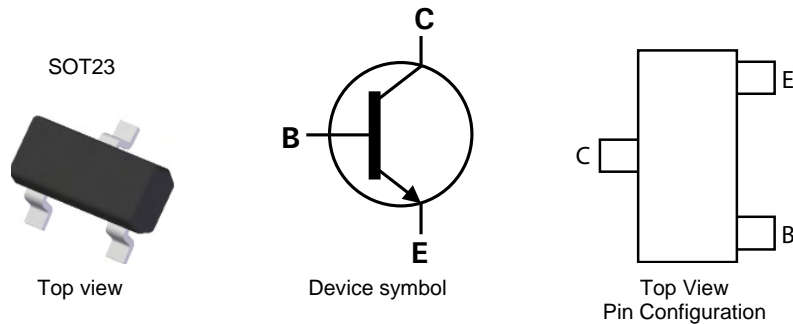
- $BV_{CE0} > 50V$
- $I_C = 2A$ Continuous Collector Current
- Low Saturation Voltage $V_{CE(sat)} < 200mV @ 1A$
- $R_{SAT} = 68m\Omega$ for a low equivalent on-resistance
- h_{FE} characterised up to 6A for high current gain hold-up
- 625mW power dissipation due to SuperSOT package
- Complementary NPN type: FMMT720
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: SOT23
- Case material: Molded Plastic. "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Copper plated Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208 ③
- Weight: 0.008 grams (Approximate)

Applications

- MOSFET Gate Driving
- DC-DC / DC-AC Converters
- Regulator
- LED driver
- Motor Control

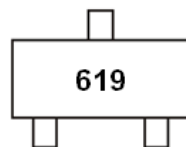


Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMT619TA	619	7	8	3,000
FMMT619TC	619	13	8	10,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See <http://www.diodes.com/> for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com>

Marking Information



619 = Product Type Marking Code

Maximum Ratings @T_A = 25°C unless otherwise specified

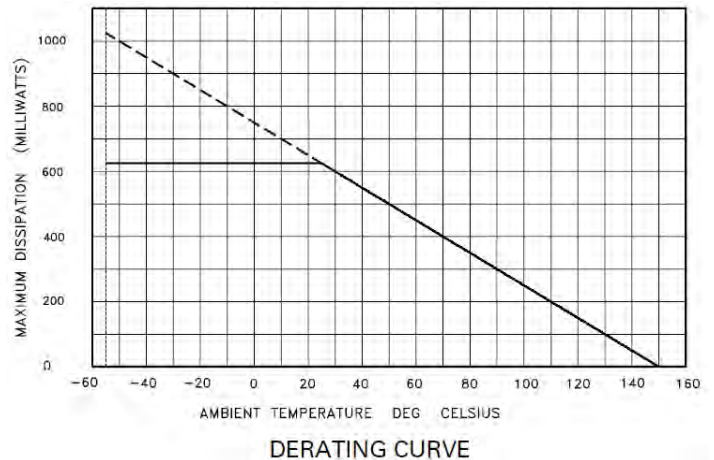
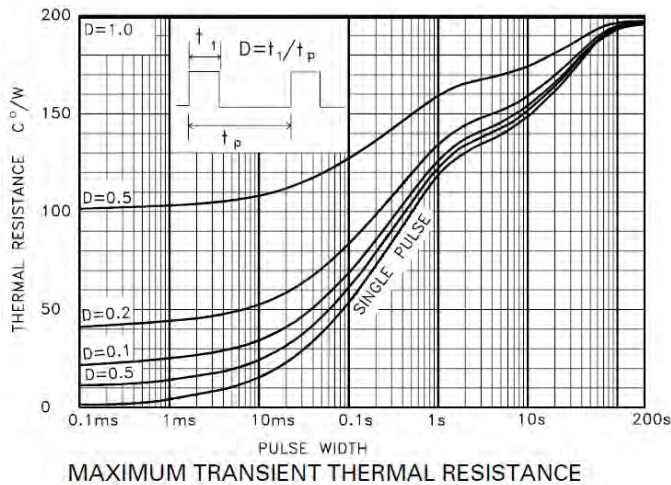
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	50	V
Collector-Emitter Voltage	V _{CEO}	50	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	I _C	2	A
Peak Pulse Current	I _{CM}	6	A
Base Current	I _B	500	mA

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	625	mW
Linear Rating Factor		5	mW/°C
Thermal Resistance, Junction to Ambient	R _{θJA}	200	°C/W
Thermal Resistance, Junction to Lead	R _{θJL}	194	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes: 5. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
6. Thermal resistance from junction to solder-point (at the end of the collector lead).

Thermal Characteristics and Derating information

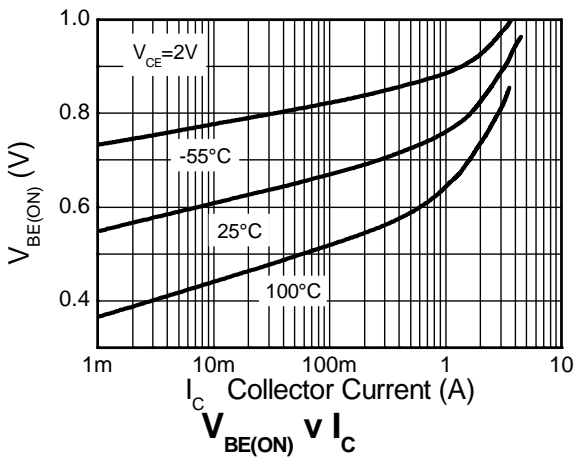
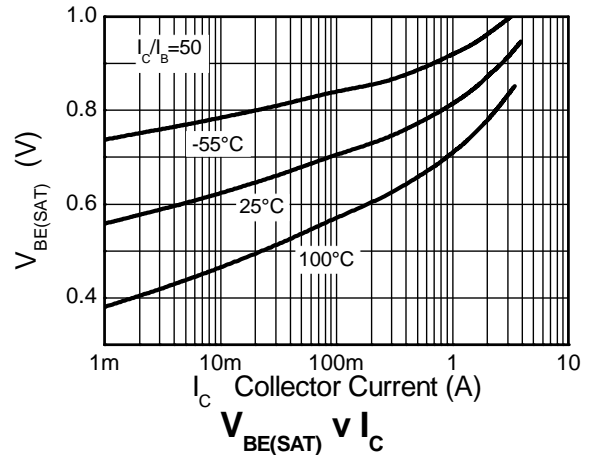
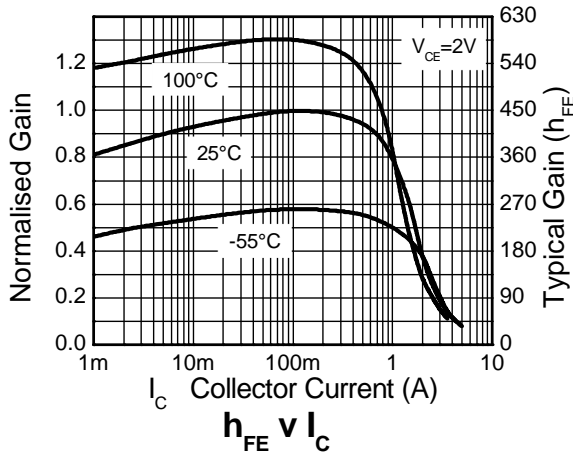
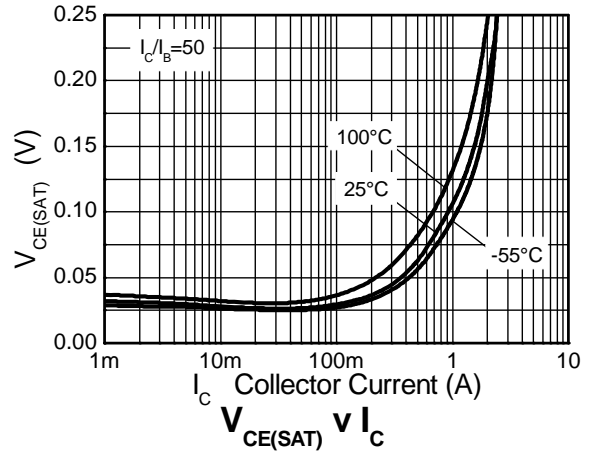
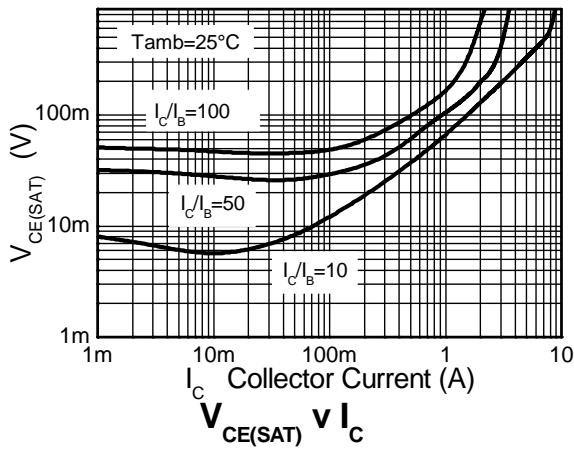


Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

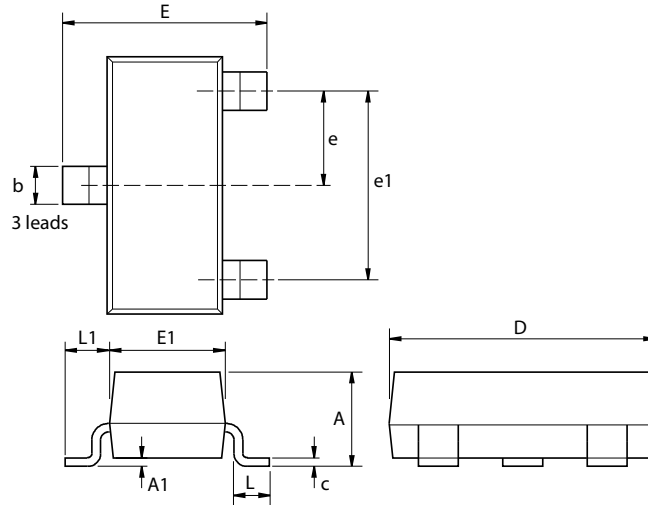
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV_{CBO}	50	190	-	V	$I_C = 100\mu\text{A}$
Collector-Emitter Breakdown Voltage (Note 7)	BV_{CEO}	50	65	-	V	$I_C = 10\text{mA}$
Emitter-Base Breakdown Voltage	BV_{EBO}	7	8.3	-	V	$I_E = 100\mu\text{A}$
Collector Cut-off Current	I_{CBO}	-	-	100	nA	$V_{CB} = 40\text{V}$
Emitter Cut-off Current	I_{EBO}	-	-	100	nA	$V_{EB} = 6\text{V}$
Collector Emitter Cut-off Current	I_{CES}	-	-	100	nA	$V_{CES} = 40\text{V}$
ON CHARACTERISTICS (Note 7)						
Static Forward Current Transfer Ratio	h_{FE}	200	400	-	-	$I_C = 10\text{mA}, V_{CE} = 2\text{V}$
		300	450	-		
		200	400	-		
		100	225	-		
		-	40	-		
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	-	10	20	mV	$I_C = 0.1\text{A}, I_B = 10\text{mA}$
		-	125	200		$I_C = 1\text{A}, I_B = 10\text{mA}$
		-	150	220		$I_C = 2\text{A}, I_B = 50\text{mA}$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	-	0.87	1.0	V	$I_C = 2\text{A}, I_B = 50\text{mA}$
Base-Emitter Saturation Voltage	$V_{BE(on)}$	-	0.80	1.0	V	$I_C = 2\text{A}, V_{CE} = 2\text{V}$
SMALL SIGNAL CHARACTERISTICS						
Transition Frequency	f_T	100	165	-	MHz	$I_C = 50\text{mA}, V_{CE} = 10\text{V}, f = 100\text{MHz}$
Collector Output Capacitance	C_{obo}	-	12	20	pF	$V_{CB} = 10\text{V}, f = 1\text{MHz}$
Turn-On Time	$t_{(on)}$	-	170	-	ns	$V_{CC} = 10\text{V}, I_C = 1\text{A},$
Turn-Off Time	$t_{(off)}$	-	750	-	ns	$I_{B1} = -I_{B2} = 10\text{mA}$

Notes: 7. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$

Typical Electrical Characteristics



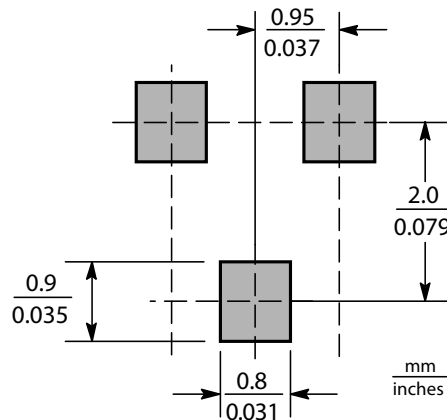
Package Outline Dimensions



Dim.	Millimeters		Inches		Dim.	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	-	1.12	-	0.044	e1	1.90 NOM		0.075 NOM	
A1	0.01	0.10	0.0004	0.004	E	2.10	2.64	0.083	0.104
b	0.30	0.50	0.012	0.020	E1	1.20	1.40	0.047	0.055
c	0.085	0.20	0.003	0.008	L	0.25	0.60	0.0098	0.0236
D	2.80	3.04	0.110	0.120	L1	0.45	0.62	0.018	0.024
e	0.95 NOM		0.037 NOM		-	-	-	-	-

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

Suggested Pad Layout



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